# Very Low Forward Voltage Trench-based Schottky Rectifier

## Exceptionally Low $V_F = 0.50$ V at $I_F = 5$ A

#### Features

- Fine Lithography Trench–based Schottky Technology for Very Low Forward Voltage and Low Leakage
- Fast Switching with Exceptional Temperature Stability
- Low Power Loss and Lower Operating Temperature
- Higher Efficiency for Achieving Regulatory Compliance
- Low Thermal Resistance
- High Surge Capability
- Pb-Free and Halide-Free Packages are Available

#### **Typical Applications**

- Switching Power Supplies including Notebook / Netbook Adapters, ATX and Flat Panel Display
- High Frequency and DC–DC Converters
- Freewheeling and OR-ing diodes
- Reverse Battery Protection
- Instrumentation

#### **Mechanical Characteristics**

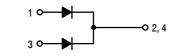
- Case: Epoxy, Molded
- Epoxy Meets Flammability Rating UL 94-0 @ 0.125 in
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Maximum for 10 sec

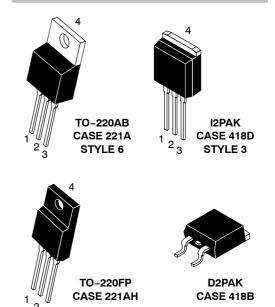


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#### **PIN CONNECTIONS**





#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

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#### MAXIMUM RATINGS

Rating			Value	Unit	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	100	V	
Average Rectified Forward Current (Rated $V_R$ , $T_C$ = 130°C)	Per device Per diode	I <sub>F(AV)</sub>	20 10	A	
Peak Repetitive Forward Current (Rated $V_R$ , Square Wave, 20 kHz, $T_C$ = 125°C)	Per device Per diode	I <sub>FRM</sub>	40 20	A	
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)		I <sub>FSM</sub>	150	A	
Operating Junction Temperature		Τ <sub>J</sub>	-40 to +150	°C	
Storage Temperature		T <sub>stg</sub>	-40 to +150	°C	
Voltage Rate of Change (Rated V <sub>R</sub> )		dv/dt	10,000	V/μs	

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

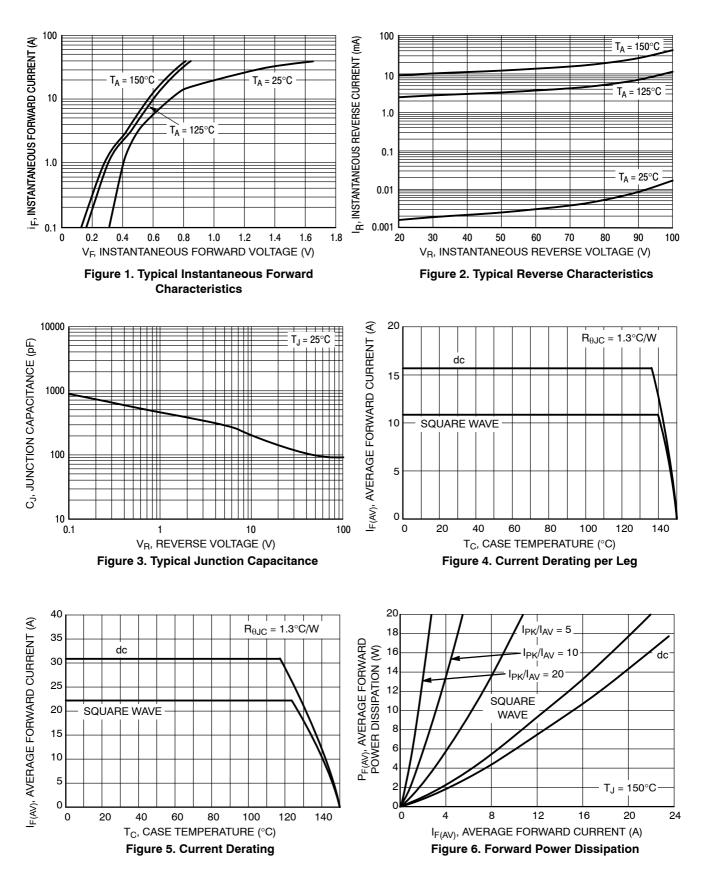
#### THERMAL CHARACTERISTICS

Rating	Symbol	NTST20U100CTG, NTSB20U100CT-1G	NTSB20U100CTG	NTSJ20U100CTG	Unit
Maximum Thermal Resistance per Diode Junction-to-Case Junction-to-Ambient	$R_{ heta JC} \\ R_{ heta JA}$	2.5 70	1.24 46.7	4.20 105	°C/W °C/W

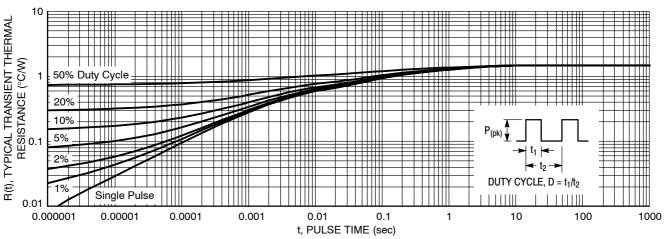
#### ELECTRICAL CHARACTERISTICS (Per Leg unless otherwise noted)

Rating	Symbol	Тур	Мах	Unit
Maximum Instantaneous Forward Voltage (Note 1)	٧ <sub>F</sub>			V
(I <sub>F</sub> = 5 A, T <sub>J</sub> = 25°C) (I <sub>F</sub> = 10 A, T <sub>J</sub> = 25°C)		0.55 0.65	0.79	
$(I_F = 5 \text{ A}, T_J = 125^{\circ}\text{C})$ $(I_F = 10 \text{ A}, T_J = 125^{\circ}\text{C})$		0.50 0.58	_ 0.68	
	I <sub>R</sub>	17 5.3		μA mA
(Rated dc Voltage, $T_J = 25^{\circ}C$ ) (Rated dc Voltage, $T_J = 125^{\circ}C$ )		_ 12	800 25	μA mA

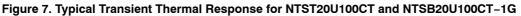
1. Pulse Test: Pulse Width = 300  $\mu s,$  Duty Cycle  $\,\leq\,$  2.0%

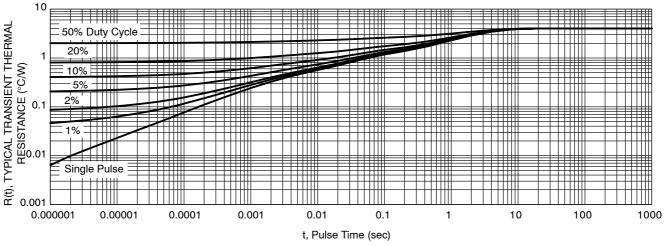


#### **TYPICAL CHARACTERISITICS**

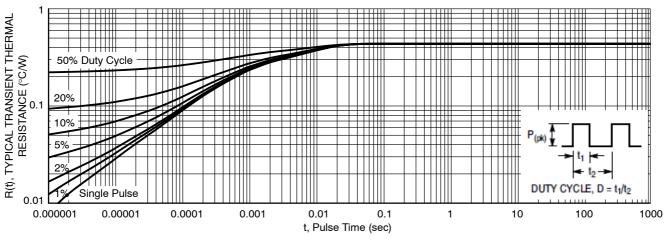


#### **TYPICAL CHARACTERISITICS**











#### **ORDERING INFORMATION**

Device	Device Package	
NTST20U100CTG	TO-220AB (Pb-Free)	50 Units / Rail
NTSB20U100CT-1G	l <sup>2</sup> PAK (Pb–Free)	50 Units / Rail
NTSJ20U100CTG	TO-220FP 50 Units / Rail (Halide-Free)	
NTSB20U100CTG	D <sup>2</sup> PAK (Pb–Free)	50 Units / Rail
NTSB20U100CTT4G	D <sup>2</sup> PAK (Pb–Free)	800 / Tape & Reel

**MARKING DIAGRAMS** 

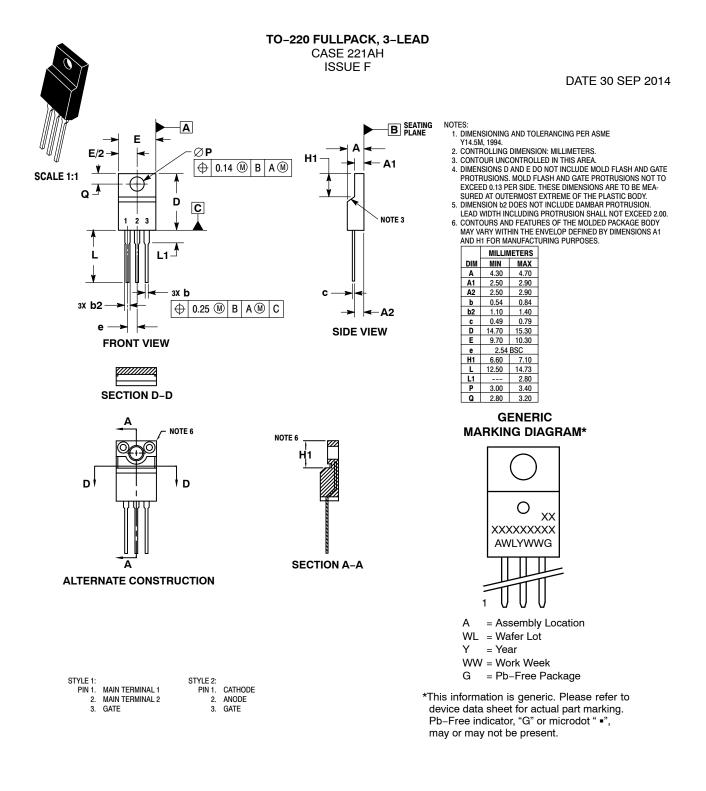
#### AYWW AYWW TS20U10CG AYWW AYWW TS20U10CG TS20U10Cx TS20U10CG AKA AKA AKA AKA TO-220FP I<sup>2</sup>PAK D<sup>2</sup>PAK TO-220AB y Location A

A	= Assembly
V	Veer

Y	= year
	14/

- WW = Work Week = Polarity Designator
- AKA = G or H
- х G = Pb-Free Package
- Н = Halide-Free Package

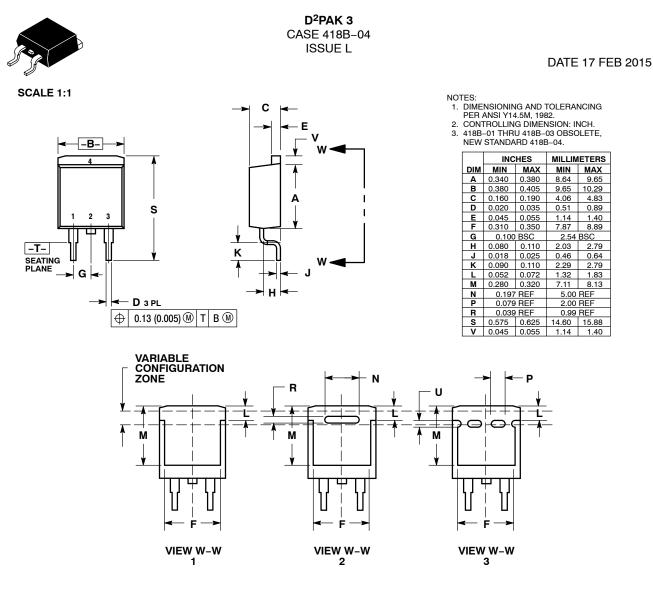
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DESCRIPTION:	TO-220 FULLPACK, 3-LEAD		PAGE 1 OF 1	

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STYLE 1:	STYLE 2:	STYLE 3:	STYLE 4:	STYLE 5:	STYLE 6:
PIN 1. BASE	PIN 1. GATE	PIN 1. ANODE	PIN 1. GATE	PIN 1. CATHODE	PIN 1. NO CONNECT
2. COLLECTOR	2. DRAIN	2. CATHODE	2. COLLECTOR	2. ANODE	2. CATHODE
3. EMITTER	<ol><li>SOURCE</li></ol>	<ol><li>ANODE</li></ol>	3. EMITTER	<ol><li>CATHODE</li></ol>	3. ANODE
4. COLLECTOR	4. DRAIN	<ol><li>CATHODE</li></ol>	4. COLLECTOR	4. ANODE	4. CATHODE

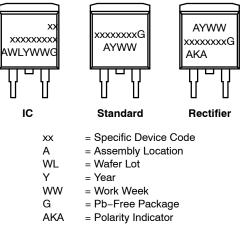
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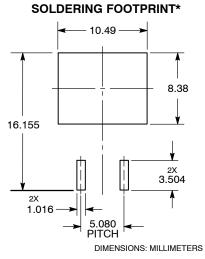
#### D<sup>2</sup>PAK 3 CASE 418B-04 ISSUE L

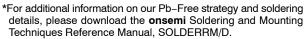
#### DATE 17 FEB 2015

#### GENERIC MARKING DIAGRAM\*



\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.





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